# S852T / S852TW

# **Vishay Semiconductors**



#### **Maximum Thermal Resistance**

Parameter	Test condition	Symbol	Value	Unit	
Junction ambient	1)	$R_{thJA}$	450	K/W	

 $<sup>\</sup>overline{}^{1)}$  on glass fibre printed board (25 x 20 x 1.5)  $\text{mm}^3$  plated with 35  $\mu m$  Cu

#### **Electrical DC Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

and								
Parameter	Test condition	Symbol	Min	Тур.	Max	Unit		
Collector-emitter cut-off current	V <sub>CE</sub> = 12 V, V <sub>BE</sub> = 0	I <sub>CES</sub>			100	μΑ		
Collector-base cut-off current	V <sub>CB</sub> = 8 V, I <sub>E</sub> = 0	I <sub>CBO</sub>			100	nA		
Emitter-base cut-off current	V <sub>EB</sub> = 1 V, I <sub>C</sub> = 0	I <sub>EBO</sub>			1	μΑ		
Collector-emitter breakdown voltage	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 0	V <sub>(BR)CEO</sub>	6			V		
Collector-emitter saturation voltage	$I_C = 5 \text{ mA}, I_B = 0.5 \text{ mA}$	V <sub>CEsat</sub>		0.1	0.4	V		
DC forward current transfer ratio	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 1 mA	h <sub>FE</sub>	40	90	150			

#### **Electrical AC Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Transition frequency	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 1 mA, f = 500 MHz	f <sub>T</sub>		4.7		GHz
	$V_{CE} = 2 \text{ V, } I_{C} = 1.5 \text{ mA,}$ f = 500 MHz	f <sub>T</sub>		5.2		GHz
Collector-base capacitance	V <sub>CB</sub> = 1 V, f = 1 MHz	C <sub>cb</sub>		pF		
Noise figure	$Z_S = Z_{Sopt}$ , f = 450 MHz, $V_{CE} = 2$ V, $I_C = 0.5$ mA	F <sub>opt</sub>		1.1		dB
	$Z_S = Z_{Sopt}$ , f = 945 MHz, $V_{CE} = 3 \text{ V}$ , $I_C = 1 \text{ mA}$	F <sub>opt</sub>		1.8		dB
	$Z_S = Z_{Sopt}$ , f = 945 MHz, $V_{CE} = 2 \text{ V}$ , $I_C = 1.5 \text{ mA}$	F <sub>opt</sub>		2		dB
Power gain	$V_{CE} = 2 \text{ V, } I_{C} = 0.5 \text{ mA,}$ f = 450MHz	G <sub>pe</sub> @F <sub>opt</sub>		11.5		dB
	$V_{CE} = 3 \text{ V, } I_{C} = 1 \text{ mA,}$ f = 945 MHz	G <sub>pe</sub> @F <sub>opt</sub>		10.5		dB
	$V_{CE} = 2 \text{ V, } I_{C} = 1.5 \text{ mA,}$ f = 945 MHz	G <sub>pe</sub> @F <sub>opt</sub>		12		dB
Collector current for f <sub>T</sub> max	V <sub>CE</sub> = 2 V, f = 500 MHz	I <sub>C</sub>		3		mA
Real part of input impedance	$V_{CE} = 3 \text{ V, } I_{C} = 1 \text{ mA,}$ f = 945 MHz	Re <sub>(h11e)</sub>		50		Ω
	$V_{CE} = 2 \text{ V, } I_{C} = 1.5 \text{ mA,}$ f = 945 MHz	Re <sub>(h11e)</sub>		50		Ω

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#### **Common Emitter S-Parameters**

V <sub>CE</sub> /V	I <sub>C</sub> /mA	f/MHz	S.	11	S	21	S.	12	S	22
			LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG	LIN MAG	ANG
				deg		deg		deg		deg
2	0.5	100	9.976	-3.8	1.71	174.9	0.015	86.8	0.998	-2.3
		200	0.969	-7.9	1.71	168.9	0.029	83.4	0.993	-4.7
		300	0.955	-11.7	1.70	163.3	0.044	80.0	0.984	-6.7
		400	0.939	-15.5	1.68	157.7	0.058	76.8	0.974	-8.7
		500	0.920	-18.9	1.64	151.9	0.070	73.6	0.959	-10.6
		600	0.901	-22.4	1.62	147.2	0.082	71.5	0.948	-12.4
		700	0.881	-25.8	1.58	142.2	0.093	69.0	0.935	-13.9
		800	0.861	-28.9	1.56	137.6	0.104	66.7	0.922	-15.5
		900	0.838	-32.3	1.53	133.1	0.114	65.0	0.909	-17.2
		1000	0.818	-35.4	1.50	129.4	0.121	63.5	0.898	-18.6
		1100	0.793	-38.8	1.49	125.1	0.130	61.8	0.884	-19.7
		1200	0.772	-41.5	1.46	121.3	0.138	60.4	0.873	-21.3
		1300	0.746	-45.1	1.44	117.2	0.148	58.6	0.859	-22.6
2	1.5	100	0.972	-7.5	4.84	170.9	0.016	84.8	0.990	-3.9
		200	0.898	-14.5	4.69	161.7	0.031	79.8	0.972	-7.4
		300	0.858	-21.0	4.49	153.1	0.045	75.1	0.944	-10.6
		400	0.811	-27.0	4.27	145.1	0.057	71.5	0.913	-13.1
		500	0.762	-32.2	4.01	137.8	0.067	68.3	0.880	-15.3
		600	0.710	-36.8	3.77	131.3	0.077	65.9	0.849	-16.8
		700	0.662	-40.3	3.55	125.3	0.085	63.6	0.820	-17.8
		800	0.617	-43.8	3.33	120.0	0.093	62.1	0.796	-18.7
	_	900	0.576	-46.9	3.15	115.1	0.099	61.2	0.775	-19.5
		1000	0.540	-50.0	2.98	110.7	0.106	60.3	0.756	-20.3
	_	1100	0.502	-52.4	2.82	106.5	0.113	59.5	0.740	-20.8
		1200	0.470	-54.8	2.69	102.8	0.118	59.3	0.724	-21.4
		1300	0.439	-57.6	2.56	99.0	0.123	58.7	0.710	-21.7

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# Typical Characteristics (Tamb = 25 °C unless otherwise specified)

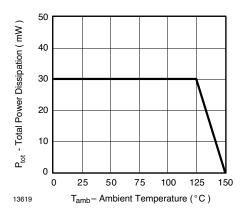


Figure 1. Total Power Dissipation vs. Ambient Temperature

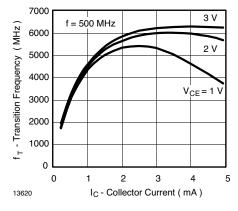


Figure 2. Transition Frequency vs. Collector Current

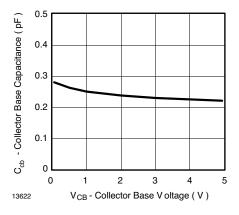


Figure 3. Collector Base Capacitance vs. Collector Base Voltage

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$$V_{CE}$$
 = 8 V,  $I_{C}$  = 25 mA,  $Z_{0}$  = 50  $\Omega$   $S_{11}$ 

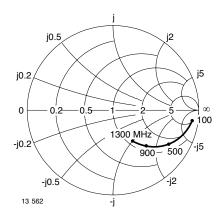


Figure 4. Input Reflection Coefficient

# S<sub>12</sub>

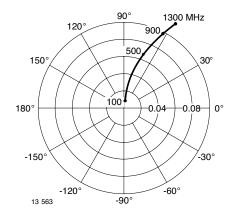


Figure 6. Reverse Transmission Coefficient

S<sub>21</sub>

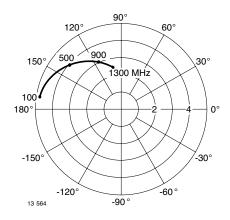


Figure 5. Forward Transmission Coefficient

S<sub>22</sub>

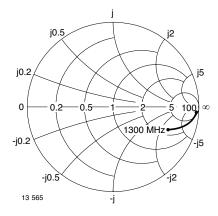
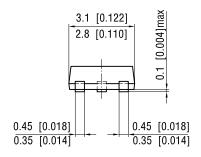
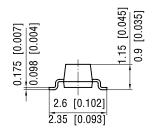


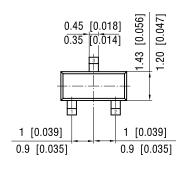
Figure 7. Output Reflection Coefficient

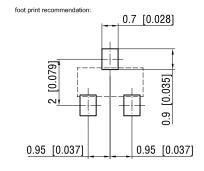
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#### Package Dimensions in mm (Inches)





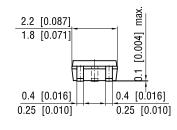


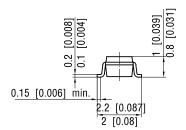


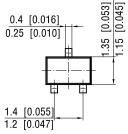
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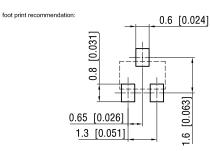
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#### Package Dimensions in mm (Inches)









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#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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